



PSMN7R8-120PS

N-channel 120V 7.9mΩ standard level MOSFET in TO220

25 January 2013

Product data sheet

1. General description

Standard level N-channel MOSFET in TO220 package qualified to 175C. This product is designed and qualified for use in a wide range of industrial, communications and power supply equipment.

2. Features and benefits

- High efficiency due to low switching and conduction losses
- TO220 package
- Suitable for standard level gate drive

3. Applications

- AC-to-DC power supply
- Synchronous rectification
- Motor control

4. Quick reference data

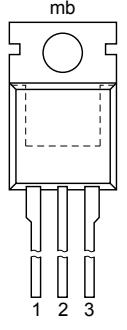
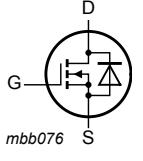
Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{DS}	drain-source voltage	$T_j \geq 25 \text{ }^\circ\text{C}; T_j \leq 175 \text{ }^\circ\text{C}$	-	-	120	V
I_D	drain current	$T_{mb} = 25 \text{ }^\circ\text{C}; V_{GS} = 10 \text{ V}$; Fig. 1	-	-	70	A
P_{tot}	total power dissipation	$T_{mb} = 25 \text{ }^\circ\text{C}$; Fig. 2	-	-	349	W
Static characteristics						
R_{DSon}	drain-source on-state resistance	$V_{GS} = 10 \text{ V}; I_D = 25 \text{ A}; T_j = 25 \text{ }^\circ\text{C}$; Fig. 12	4.7	6.72	7.9	$\text{m}\Omega$
Dynamic characteristics						
Q_{GD}	gate-drain charge	$V_{GS} = 10 \text{ V}; I_D = 25 \text{ A}; V_{DS} = 60 \text{ V}$; Fig. 14 ; Fig. 15	-	50.5	-	nC
$Q_{G(tot)}$	total gate charge		-	167	-	nC
Avalanche ruggedness						
$E_{DS(AL)S}$	non-repetitive drain-source avalanche energy	$V_{GS} = 10 \text{ V}; T_{j(\text{init})} = 25 \text{ }^\circ\text{C}; I_D = 70 \text{ A}$; $V_{sup} \leq 120 \text{ V}$; unclamped; $R_{GS} = 50 \Omega$; Fig. 3	-	-	386	mJ

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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		
2	D	drain		
3	S	source		
mb	D	drain	 TO-220AB (SOT78)	

6. Ordering information

Table 3. Ordering information

Type number	Package			Version
	Name	Description	Version	
PSMN7R8-120PS	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78	

7. Marking

Table 4. Marking codes

Type number	Marking code
PSMN7R8-120PS	PSMN7R8-120PS

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage	$T_j \geq 25^\circ\text{C}$; $T_j \leq 175^\circ\text{C}$	-	120	V
V_{DGR}	drain-gate voltage	$T_j \geq 25^\circ\text{C}$; $T_j \leq 175^\circ\text{C}$; $R_{GS} = 20\text{ k}\Omega$	-	120	V
V_{GS}	gate-source voltage		-20	20	V
I_D	drain current	$V_{GS} = 10\text{ V}$; $T_{mb} = 25^\circ\text{C}$; Fig. 1	-	70	A
		$V_{GS} = 10\text{ V}$; $T_{mb} = 100^\circ\text{C}$; Fig. 1	-	70	A
I_{DM}	peak drain current	pulsed; $t_p \leq 10\text{ }\mu\text{s}$; $T_{mb} = 25^\circ\text{C}$; Fig. 4	-	280	A

Symbol	Parameter	Conditions	Min	Max	Unit
P _{tot}	total power dissipation	T _{mb} = 25 °C; Fig. 2	-	349	W
T _{stg}	storage temperature		-55	175	°C
T _j	junction temperature		-55	175	°C
T _{sld(M)}	peak soldering temperature		-	260	°C
Source-drain diode					
I _S	source current	T _{mb} = 25 °C	-	70	A
I _{SM}	peak source current	pulsed; t _p ≤ 10 µs; T _{mb} = 25 °C	-	280	A
Avalanche ruggedness					
E _{DS(AL)S}	non-repetitive drain-source avalanche energy	V _{GS} = 10 V; T _{j(init)} = 25 °C; I _D = 70 A; V _{sup} ≤ 120 V; unclamped; R _{GS} = 50 Ω; Fig. 3	-	386	mJ

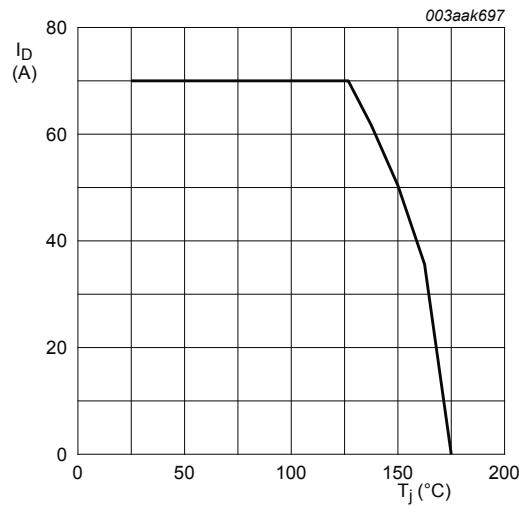


Fig. 1. Continuous drain current as a function of mounting base temperature

V_{GS} ≥ 10 V

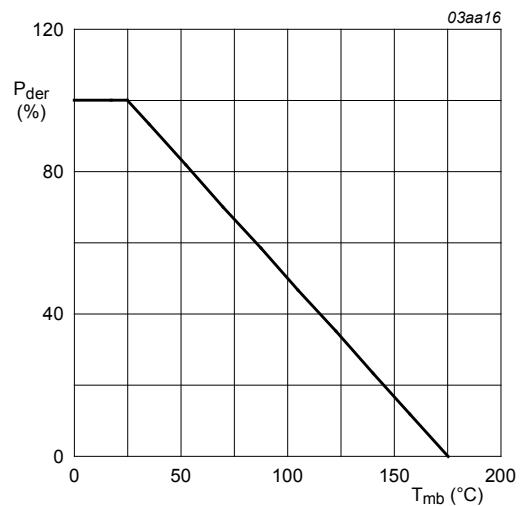


Fig. 2. Normalized total power dissipation as a function of mounting base temperature

$$P_{der} = \frac{P_{tot}}{P_{tot}(25^\circ\text{C})} \times 100 \%$$

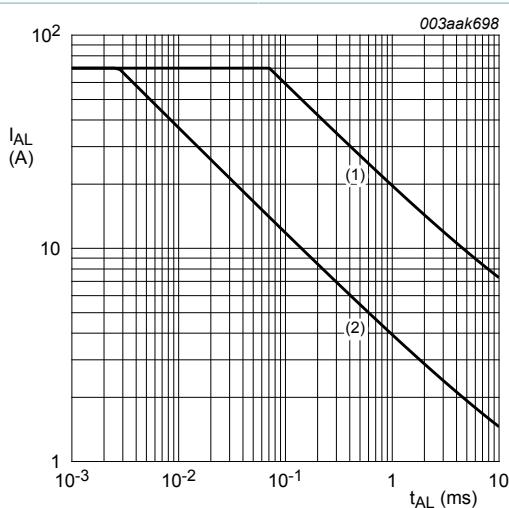


Fig. 3. Single-pulse and repetitive avalanche rating; avalanche current as a function of avalanche time

(1) Single-pulse; $T_j = 25^\circ\text{C}$.
 (2) Single-pulse; $T_j = 125^\circ\text{C}$.

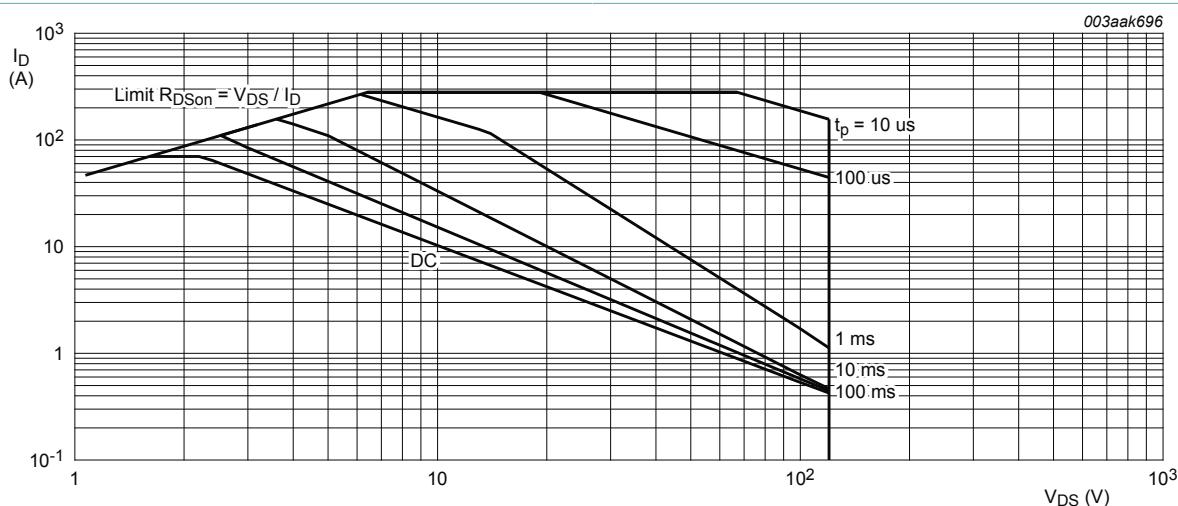


Fig. 4. Safe operating area; continuous and peak drain current as a function of drain-source voltage

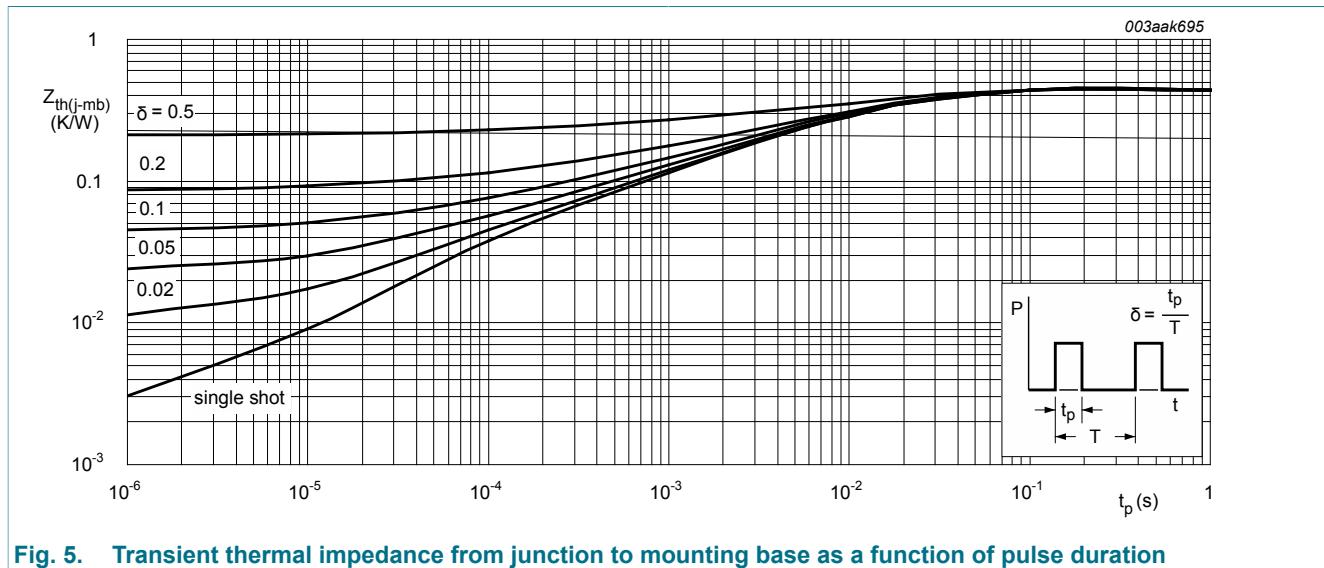
$T_{mb} = 25^\circ\text{C}$; I_{DM} is single pulse

9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	Fig. 5		-	0.35	0.43	K/W

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	vertical in free air		-	60	-	K/W



10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
Static characteristics							
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25^\circ C$		120	-	-	V
		$I_D = 250 \mu A; V_{GS} = 0 V; T_j = -55^\circ C$		108	-	-	V
Dynamic characteristics							
$V_{GS(th)}$	gate-source threshold voltage	$I_D = 1 mA; V_{DS} = V_{GS}; T_j = 25^\circ C$ Fig. 10 ; Fig. 11		2	3	4	V
		$I_D = 1 mA; V_{DS} = V_{GS}; T_j = 175^\circ C$ Fig. 10		1	-	-	V
		$I_D = 1 mA; V_{DS} = V_{GS}; T_j = -55^\circ C$ Fig. 10		-	-	4.6	V
I_{DSS}	drain leakage current	$V_{DS} = 120 V; V_{GS} = 0 V; T_j = 25^\circ C$		-	0.1	1	μA
		$V_{DS} = 120 V; V_{GS} = 0 V; T_j = 175^\circ C$		-	-	500	μA
I_{GSS}	gate leakage current	$V_{GS} = 20 V; V_{DS} = 0 V; T_j = 25^\circ C$		-	10	100	nA
		$V_{GS} = -20 V; V_{DS} = 0 V; T_j = 25^\circ C$		-	10	100	nA
R_{DSon}	drain-source on-state resistance	$V_{GS} = 10 V; I_D = 25 A; T_j = 25^\circ C$ Fig. 12		4.7	6.72	7.9	$m\Omega$
		$V_{GS} = 10 V; I_D = 25 A; T_j = 175^\circ C$ Fig. 12 ; Fig. 13		-	19.3	22.9	$m\Omega$

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
R_G	internal gate resistance (AC)	$f = 1 \text{ MHz}$		0.39	0.78	1.56	Ω
Dynamic characteristics							
$Q_{G(\text{tot})}$	total gate charge	$I_D = 25 \text{ A}; V_{DS} = 60 \text{ V}; V_{GS} = 10 \text{ V};$ Fig. 14 ; Fig. 15		-	167	-	nC
Q_{GS}	gate-source charge			-	36.9	-	nC
$Q_{GS(\text{th})}$	pre-threshold gate-source charge			-	24.2	-	nC
$Q_{GS(\text{th-pl})}$	post-threshold gate-source charge			-	12.7	-	nC
Q_{GD}	gate-drain charge			-	50.5	-	nC
$V_{GS(\text{pl})}$	gate-source plateau voltage	$I_D = 25 \text{ A}; V_{DS} = 60 \text{ V};$ Fig. 14 ; Fig. 15		-	4.5	-	V
C_{iss}	input capacitance	$V_{DS} = 60 \text{ V}; V_{GS} = 0 \text{ V}; f = 1 \text{ MHz};$ $T_j = 25 \text{ }^\circ\text{C}$; Fig. 16		-	9473	-	pF
C_{oss}	output capacitance			-	441	-	pF
C_{rss}	reverse transfer capacitance			-	298	-	pF
$t_{d(on)}$	turn-on delay time	$V_{DS} = 60 \text{ V}; R_L = 2.4 \Omega; V_{GS} = 10 \text{ V};$ $R_{G(\text{ext})} = 5 \Omega; T_j = 25 \text{ }^\circ\text{C}$		-	45.5	-	ns
t_r	rise time			-	55.3	-	ns
$t_{d(off)}$	turn-off delay time			-	151.8	-	ns
t_f	fall time			-	60.8	-	ns
Source-drain diode							
V_{SD}	source-drain voltage	$I_S = 25 \text{ A}; V_{GS} = 0 \text{ V}; T_j = 25 \text{ }^\circ\text{C};$ Fig. 17		-	0.81	1.2	V
t_{rr}	reverse recovery time	$I_S = 25 \text{ A}; dI_S/dt = -100 \text{ A}/\mu\text{s}; V_{GS} = 0 \text{ V};$ $V_{DS} = 60 \text{ V}$		-	75.7	-	ns
Q_r	recovered charge			-	264	-	nC

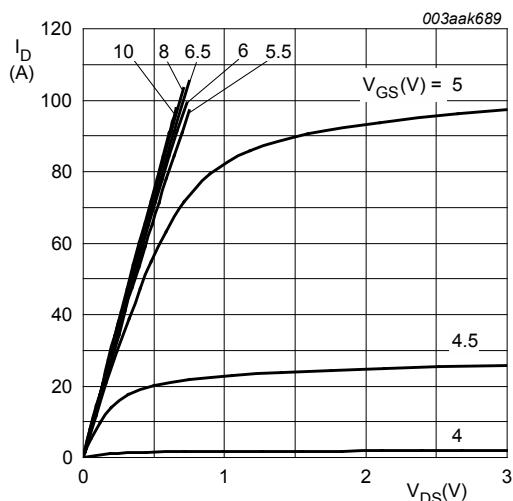


Fig. 6. Output characteristics: drain current as a function of drain-source voltage; typical values

$T_j = 25^\circ C$

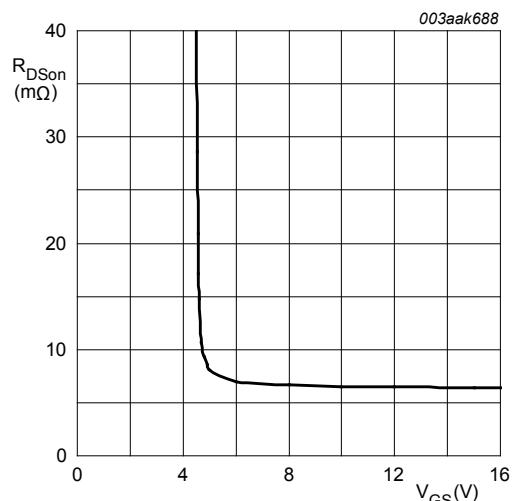


Fig. 7. Drain-source on-state resistance as a function of gate-source voltage; typical values

$T_j = 25^\circ C$

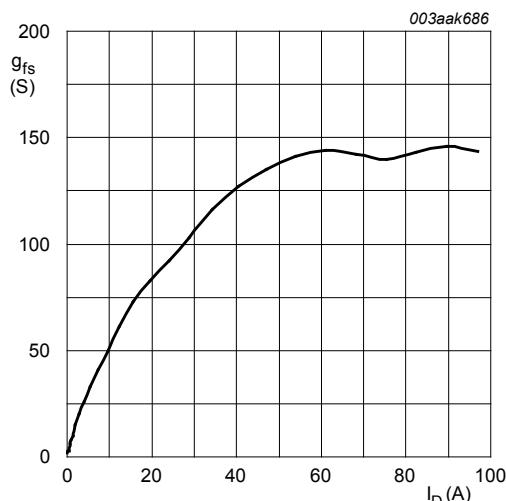


Fig. 8. Forward transconductance as a function of drain current; typical values

$T_j = 25^\circ C; V_{DS} = 10 V$

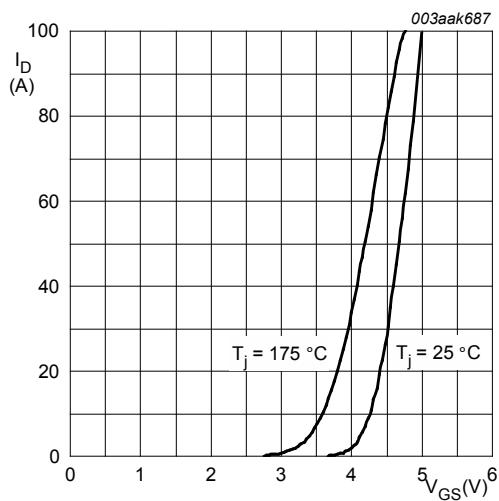


Fig. 9. Transfer characteristics: drain current as a function of gate-source voltage; typical values

$V_{DS} > I_D \times R_{DS(on)}$

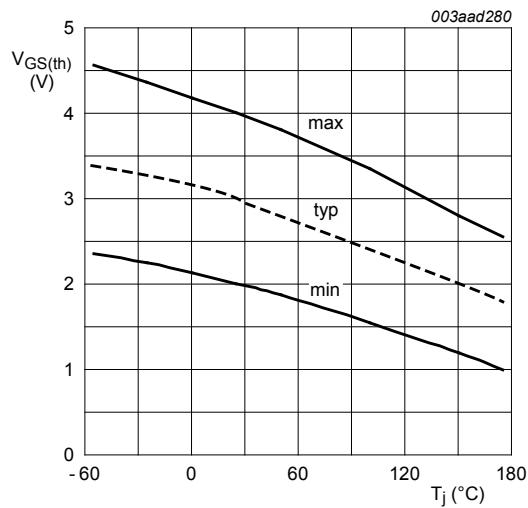


Fig. 10. Gate-source threshold voltage as a function of junction temperature

$I_D = 1 \text{ mA}; V_{DS} = V_{GS}$

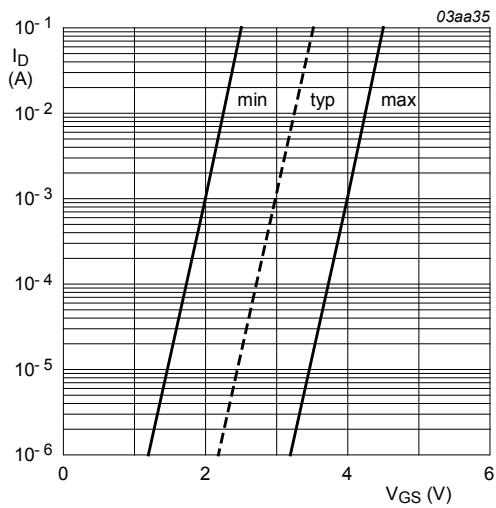


Fig. 11. Sub-threshold drain current as a function of gate-source voltage

$T_j = 25^\circ\text{C}; V_{DS} = 5\text{V}$

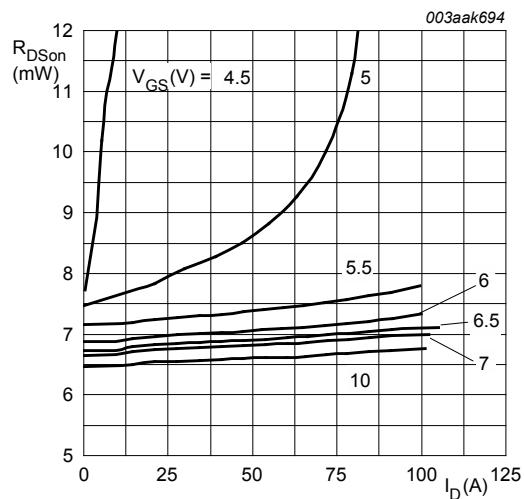


Fig. 12. Drain-source on-state resistance as a function of drain current; typical values

$T_j = 25^\circ\text{C}$

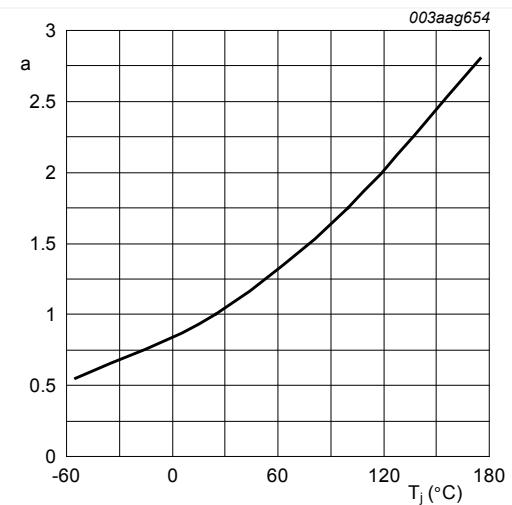


Fig. 13. Normalized drain-source on-state resistance factor as a function of junction temperature

$$a = \frac{R_{DSon}}{R_{DSon}(25^\circ\text{C})}$$

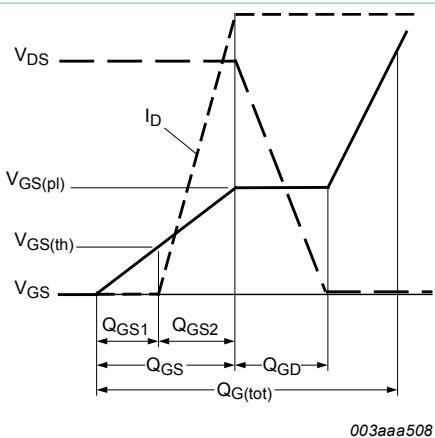


Fig. 14. Gate charge waveform definitions

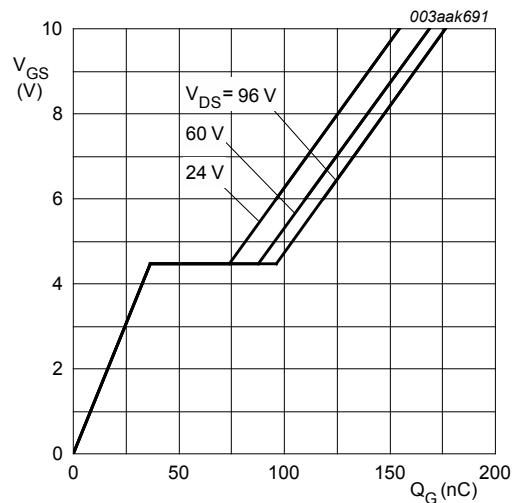


Fig. 15. Gate-source voltage as a function of gate charge; typical values

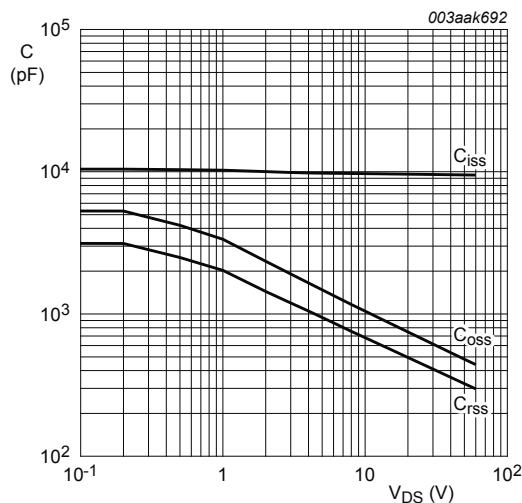
 $T_j = 25^\circ\text{C}; I_D = 25\text{A}$


Fig. 16. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

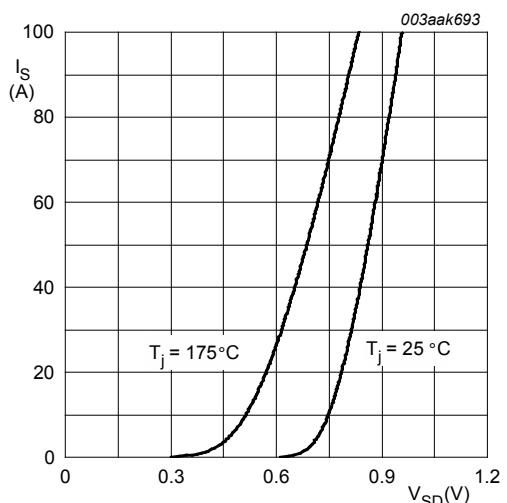
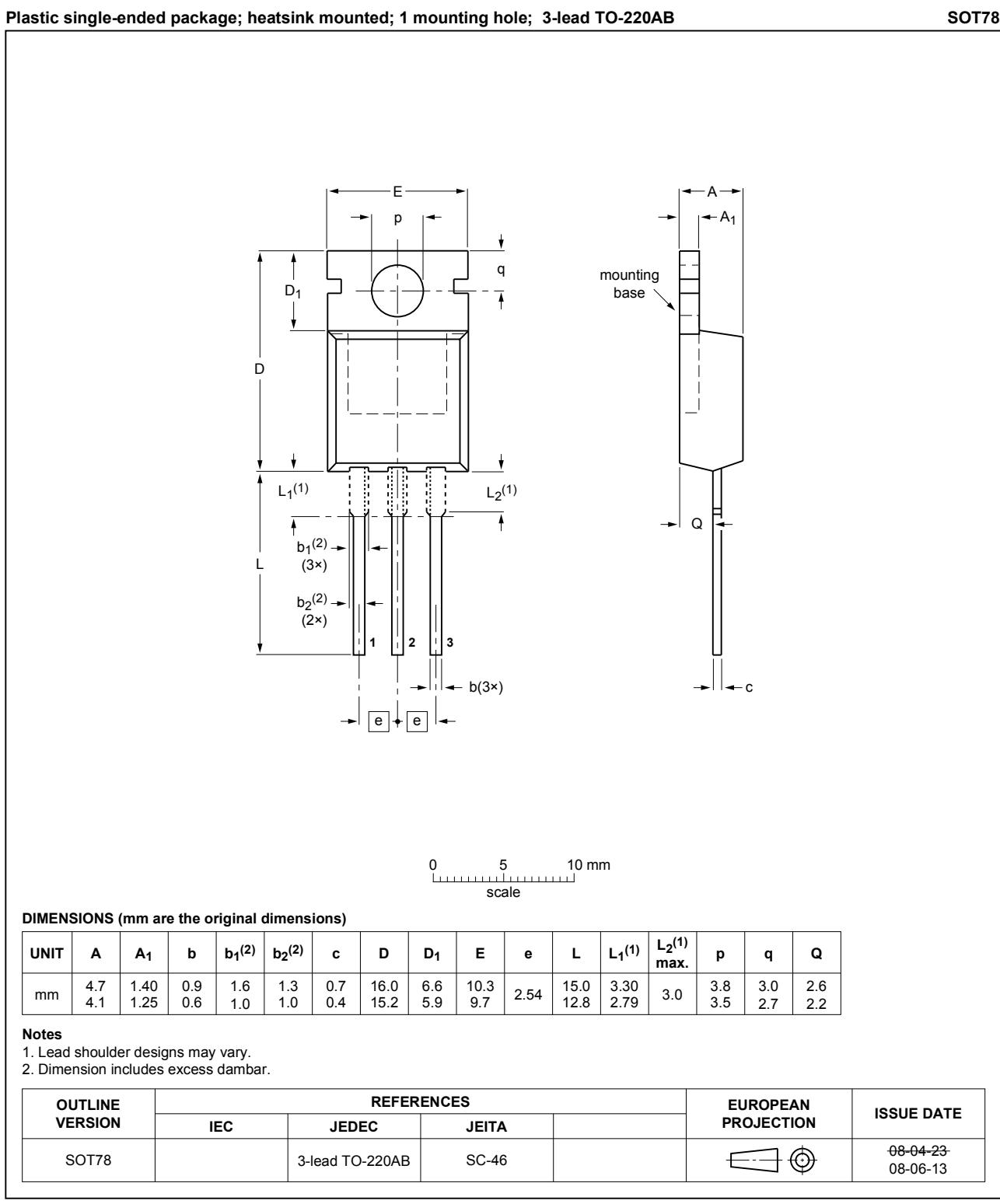
 $V_{GS} = 0\text{ V}; f = 1\text{ MHz}$


Fig. 17. Source (diode forward) current as a function of source-drain (diode forward) voltage; typical values

 $V_{GS} = 0\text{ V}$

11. Package outline



12. Legal information

12.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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